# BLS9G2729L-350: BLS9G2729LS-350 LDMOS S-band radar power transistor

**AMPLEON** 

Rev. 1 — 13 April 2017

Product data sheet

# **Product profile**

#### 1.1 General description

350 W LDMOS power transistor for S-band applications in the frequency range from 2.7 GHz to 2.9 GHz.

#### Test information Table 1.

Typical RF performance at  $T_{case}$  = 25 °C;  $t_{p}$  = 300  $\mu$ s;  $\delta$  = 10 %;  $I_{Dq}$  = 400 mA; in a class-AB demo circuit.

Test signal	f	V <sub>DS</sub>	$P_L$	G <sub>p</sub>	$\eta_{D}$
	(GHz)	(V)	(W)	(dB)	(%)
pulsed RF	2.7 to 2.9	28	320	14	50

#### 1.2 Features and benefits

- High efficiency
- Excellent ruggedness
- Designed for S-band operations
- Excellent thermal stability
- Easy power control
- Integrated dual sided ESD protection enables excellent off-state isolation
- High flexibility with respect to pulse formats
- Internally matched for ease of use
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

#### 1.3 Applications

■ S-band radar applications in the frequency range from 2.7 GHz to 2.9 GHz

# 2. Pinning information

Table 2. Pinning

Pin	Description		Simplified outline	Graphic symbol
BLS9G27	29L-350 (SOT502A)			
1	drain			,
2	gate		5 1 3	1 
3	source	[1]		2 — 3 3 sym112
BLS9G27	29LS-350 (SOT502B)			
1	drain			
2	gate		1 1 3	1 
3	source	<u>[1]</u>	2	2 — 3 sym112

<sup>[1]</sup> Connected to flange.

# 3. Ordering information

Table 3. Ordering information

Type number	Packag	Package			
	Name	Description	Version		
BLS9G2729L-350	-	flanged ceramic package; 2 mounting holes; 2 leads	SOT502A		
BLS9G2729LS-350	-	earless flanged ceramic package; 2 leads	SOT502B		

# 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage		-	65	V
$V_{GS}$	gate-source voltage		-6	+13	V
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature	[1]	-	225	°C

<sup>[1]</sup> Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

#### 5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$Z_{\text{th(j-mb)}}$	transient thermal impedance from junction to	T <sub>case</sub> = 85 °C; P <sub>L</sub> = 350 W		
	mounting base	$t_p$ = 100 $\mu$ s; $\delta$ = 10 %	0.07	K/W
		$t_p$ = 200 $\mu$ s; $\delta$ = 10 %	0.09	K/W
		$t_p$ = 300 $\mu$ s; $\delta$ = 10 %	0.11	K/W
		$t_p$ = 100 $\mu$ s; $\delta$ = 20 %	0.09	K/W

#### 6. Characteristics

Table 6. DC characteristics

 $T_i$  = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$V_{GS} = 0 \text{ V; } I_D = 4.5 \text{ mA}$	65	-	-	V
V <sub>GS(th)</sub>	gate-source threshold voltage	V <sub>DS</sub> = 10 V; I <sub>D</sub> = 450 mA	1.5	2	2.5	V
I <sub>DSS</sub>	drain leakage current	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 28 V	-	-	4	μΑ
I <sub>DSX</sub>	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	85	-	Α
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 11 V; V <sub>DS</sub> = 0 V	-	-	400	nA
9 <sub>fs</sub>	forward transconductance	V <sub>DS</sub> = 10 V; I <sub>D</sub> = 450 A	-	4.2	-	S
R <sub>DS(on)</sub>	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 V;$ $I_D = 15.75 A$	-	0.030	-	Ω

Table 7. RF characteristics

Test signal: pulsed RF;  $t_p$  = 300  $\mu$ s;  $\delta$  = 10 %; RF performance at  $V_{DS}$  = 28 V;  $I_{Dq}$  = 400 mA;  $T_{case}$  = 25 °C; unless otherwise specified; in a class-AB production circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	P <sub>L</sub> = 320 W	12	14	-	dB
RLin	input return loss	P <sub>L</sub> = 320 W	-	-10	-	dB
$\eta_{D}$	drain efficiency	P <sub>L</sub> = 320 W	45	50	-	%
P <sub>droop(pulse)</sub>	pulse droop power	P <sub>L</sub> = 320 W	-	0.0	0.3	dB
t <sub>r</sub>	rise time	P <sub>L</sub> = 320 W	-	6	50	ns
t <sub>f</sub>	fall time	P <sub>L</sub> = 320 W	-	6	50	ns
P <sub>L(2dB)</sub>	output power at 2 dB gain compression		-	350	-	W

#### 7. Test information

#### 7.1 Ruggedness in class-AB operation

The BLS9G2729L-350 and BLS9G2729LS-350 are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions:  $V_{DS}$  = 28 V;  $I_{Dq}$  = 400 mA;  $P_{L}$  = 320 W;  $I_{Dq}$  = 300  $I_{LS}$ ;  $I_{Dq}$  = 400 mA;  $I_{Dq}$  = 400 m

## 7.2 Impedance information

Table 8. Typical impedance

f	Z <sub>S</sub>	$Z_L$
(GHz)	(Ω)	(Ω)
2.7	1.6 – j5.8	1.6 – j3.7
2.8	2.9 – j6.6	1.8 – j3.6
2.9	8.0 – j4.7	2.2 – j3.1

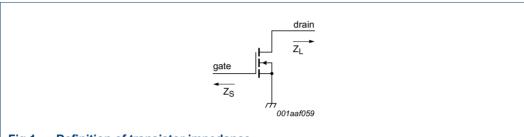


Fig 1. Definition of transistor impedance

#### 7.3 Test circuit

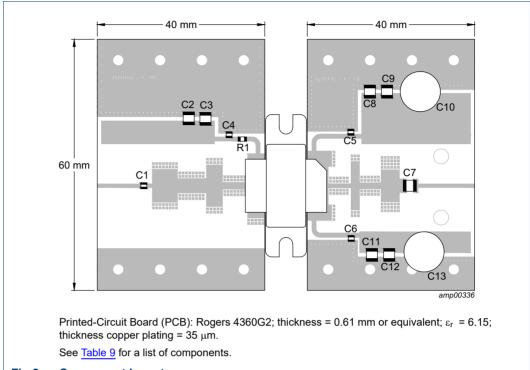
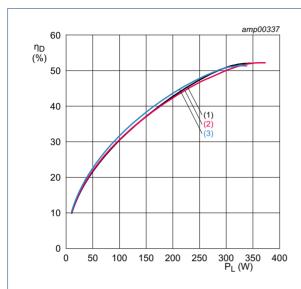


Fig 2. Component layout

Table 9.List of componentsSee Figure 2 for component layout.

Component	Description	Value	Remarks
C1	multilayer ceramic chip capacitor	12 pF	ATC800A
C2, C8, C11	multilayer ceramic chip capacitor	1 nF	ATC800B
C3, C9, C12	multilayer ceramic chip capacitor	10 μF	Murata: GRM55DR61H106KA88L
C4, C6, C6	multilayer ceramic chip capacitor	15 pF	ATC800A
C7	multilayer ceramic chip capacitor	12 pF	ATC800B
C10, C13	electrolytic capacitor	100 μF, 63 V	
R1	SMD resistor	5 Ω	0603

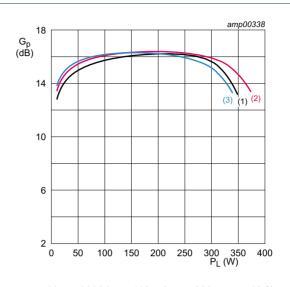
### 7.4 Graphical data



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 400 mA;  $t_p$  = 300  $\mu s;$   $\delta$  = 10 %.

- (1) f = 2700 MHz
- (2) f = 2800 MHz
- (3) f = 2900 MHz

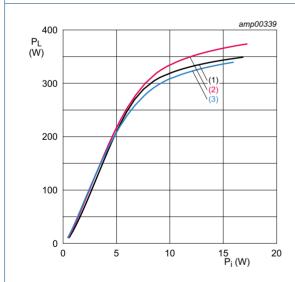
Fig 3. Drain efficiency as a function of output power; typical values



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 400 mA;  $t_p$  = 300  $\mu s;$   $\delta$  = 10 %.

- (1) f = 2700 MHz
- (2) f = 2800 MHz
- (3) f = 2900 MHz

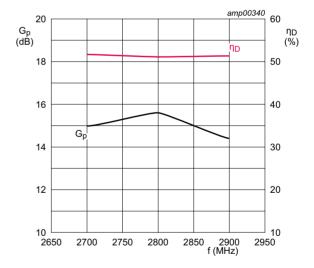
Fig 4. Power gain as a function of output power; typical values



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 400 mA;  $t_p$  = 300  $\mu$ s;  $\delta$  = 10 %.

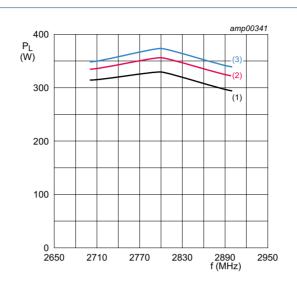
- (1) f = 2700 MHz
- (2) f = 2800 MHz
- (3) f = 2900 MHz

Fig 5. Output power as a function of input power; typical values



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 400 mA;  $P_L$  = 320 W;  $t_p$  = 300  $\mu s;$   $\delta$  = 10 %.

Fig 6. Power gain and drain efficiency as function of frequency; typical values



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 400 mA;  $t_p$  = 300  $\mu$ s;  $\delta$  = 10 %.

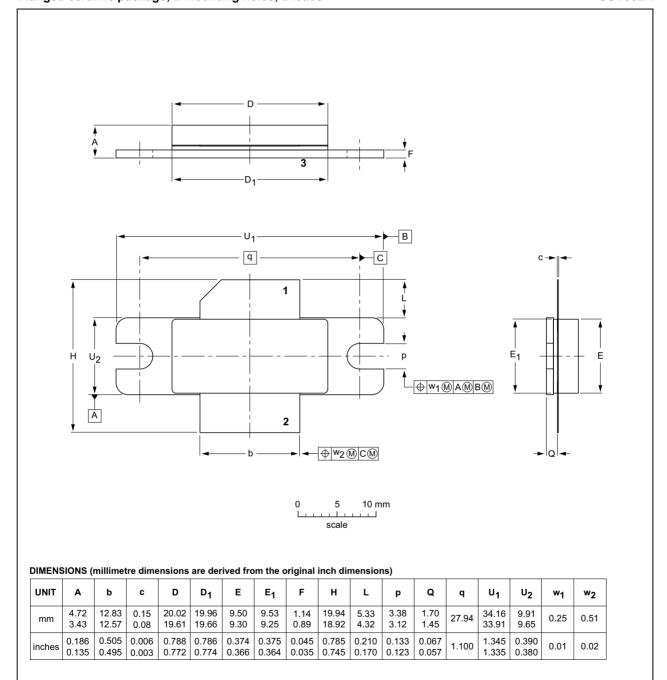
- (1) at P<sub>L(1dB)</sub>
- (2) at P<sub>L(2dB)</sub>
- (3) at P<sub>L(3dB)</sub>

Fig 7. Output power as a function of frequency; typical values

# 8. Package outline

#### Flanged ceramic package; 2 mounting holes; 2 leads

SOT502A



OUTLINE	REFERENCES					ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT502A						<del>-03-01-10 -</del> 12-05-02

Fig 8. Package outline SOT502A

#### Earless flanged ceramic package; 2 leads

SOT502B

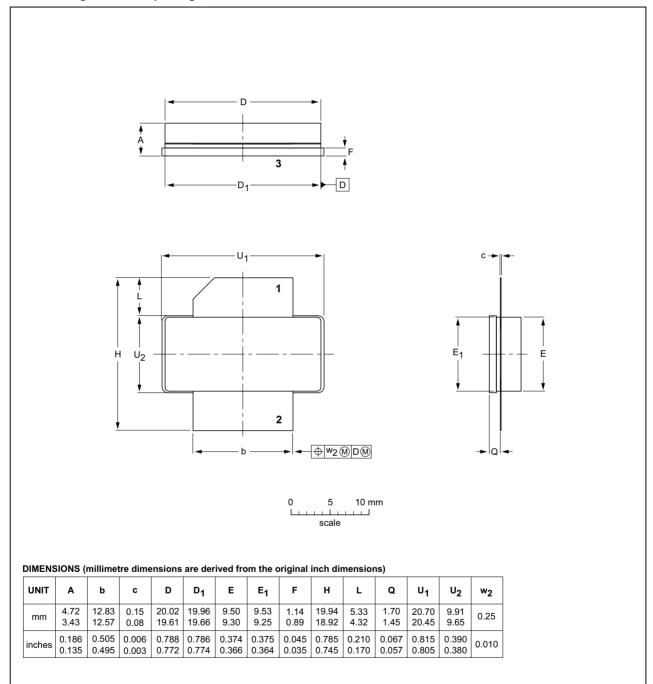


Fig 9. Package outline SOT502B

IEC

OUTLINE

VERSION

SOT502B

JEITA

**REFERENCES** 

**JEDEC** 

**ISSUE DATE** 

07-05-09

12-05-02

EUROPEAN

**PROJECTION** 

# 9. Handling information

#### **CAUTION**



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

Table 10. ESD sensitivity

ESD model	Class
Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002	C2A [1]
Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001	2 [2]

- [1] CDM classification C2A is granted to any part that passes after exposure to an ESD pulse of 500 V, but fails after exposure to an ESD pulse of 750 V.
- [2] HBM classification 2 is granted to any part that passes after exposure to an ESD pulse of 2000 V, but fails after exposure to an ESD pulse of 4000 V.

#### 10. Abbreviations

Table 11. Abbreviations

Acronym	Description
ESD	ElectroStatic Discharge
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
MTF	Median Time to Failure
S-band	Short wave band
SMD	Surface Mounted Device
VSWR	Voltage Standing-Wave Ratio

# 11. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLS9G2729L-350_2729LS-350 v.1	20170413	Product data sheet		-

# 12. Legal information

#### 12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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# BLS9G2729L(S)-350

#### **LDMOS S-band radar power transistor**

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# BLS9G2729L(S)-350

## **LDMOS S-band radar power transistor**

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